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July 2008

## FDW2501NZ

AIRCHIL

## **Dual N-Channel 2.5V Specified PowerTrench® MOSFET**

### **General Description**

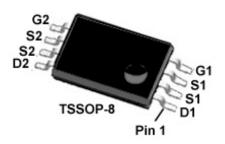
This N-Channel 2.5V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

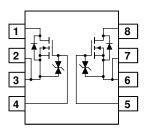
### Applications

- · Load switch
- Motor drive
- DC/DC conversion
- Power management

### Features

- 5.5 A, 20 V.  $R_{DS(ON)} = 18 \ m\Omega \ @V_{GS} = 4.5V$  $R_{DS(ON)} = 25 \ m\Omega \ @V_{GS} = 2.5V$
- Extended  $V_{GSS}$  range (±12V) for battery applications
- ESD protection diode (note 3)
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$
- Low profile TSSOP-8 package





### Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		20	V
V <sub>GSS</sub>	Gate-Source Voltage		±12	V
I <sub>D</sub>	Drain Current – Continuous	(Note 1a)	5.5	А
	– Pulsed		30	
P <sub>D</sub>	Power Dissipation	(Note 1a)	1.0	W
		(Note 1b)	0.6	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C
Therma	I Characteristics	<u>.</u>		
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	100	°C/W
		(Note 1b)	125	

## **Package Marking and Ordering Information**

 Device Marking	Device	Reel Size	Tape width	Quantity
2501NZ	FDW2501NZ	13"	12mm	2500 units

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Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Char	acteristics			J	J	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	20			V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		14		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 16 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			1	μA
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{GS} = 12 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			10	μA
I <sub>GSSR</sub>	Gate-Body Leakage, Reverse	$V_{GS} = -12 \ V,  V_{DS} = 0 \ V$			-10	μA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	0.6	1.0	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		-3		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = 4.5 \; V,  \  \  I_D = 5.5 \; A \\ V_{GS} = 2.5 \; V,  \  \  I_D = 5 \; A \\ V_{GS} = 4.5 \; V, \; I_D = 5.5 \; A, \; T_J \!=\! 125^\circ \! C \end{array} $		14 19 19	18 25 29	mΩ
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = 4.5 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	30			Α
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = 5 V$ , $I_{D} = 5.5 A$		30		S
Dvnamio	Characteristics	·		•	•	•
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 10 V$ , $V_{GS} = 0 V$ ,		1286		pF
C <sub>oss</sub>	Output Capacitance	f = 1.0  MHz		305		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	7		161		pF
Switchir	g Characteristics (Note 2)	·	•	•	•	•
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = 10 V$ , $I_D = 1 A$ ,		10	20	ns
tr	Turn–On Rise Time	$V_{GS} = 4.5 V$ , $R_{GEN} = 6 \Omega$		14	25	ns
d(off)	Turn–Off Delay Time	-		25	40	ns
t <sub>f</sub>	Turn–Off Fall Time			8	16	ns
Qg	Total Gate Charge	$V_{DS} = 10 V$ , $I_{D} = 5.5 A$ ,		12	17	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 4.5 V$		2.6		nC
Q <sub>gd</sub>	Gate-Drain Charge	1		3		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
I <sub>s</sub>	Maximum Continuous Drain–Source				1.0	Α
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = 1.0 A$ (Note 2)		0.7	1.2	V

 R<sub>BJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>BJC</sub> is guaranteed by design while R<sub>BCA</sub> is determined by the user's board design.

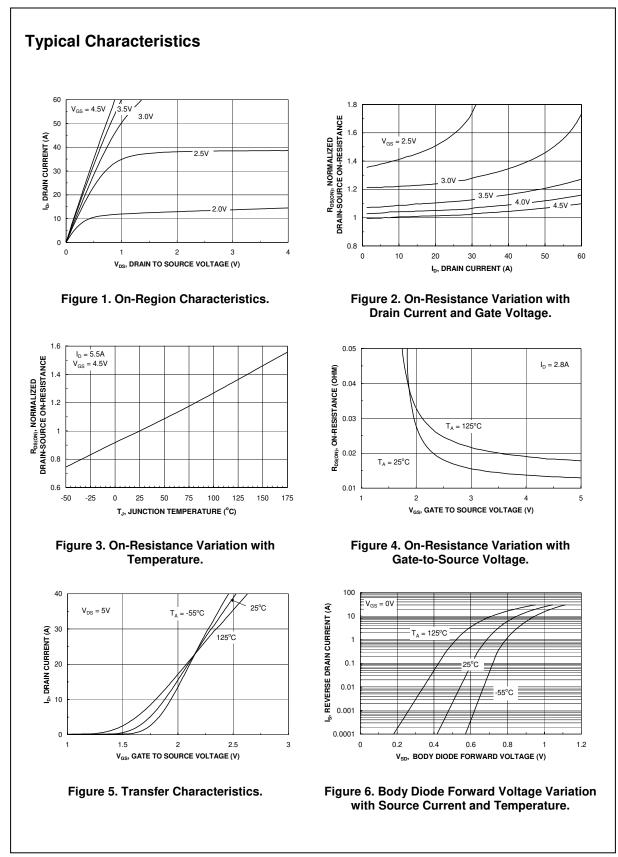
a)  $\rm R_{\rm 6JA}$  is 100°C/W (steady state) when mounted on a 1 inch² copper pad on FR-4.

b)  $R_{\theta JA}$  is 125°C/W (steady state) when mounted on a minimum copper pad on FR-4.

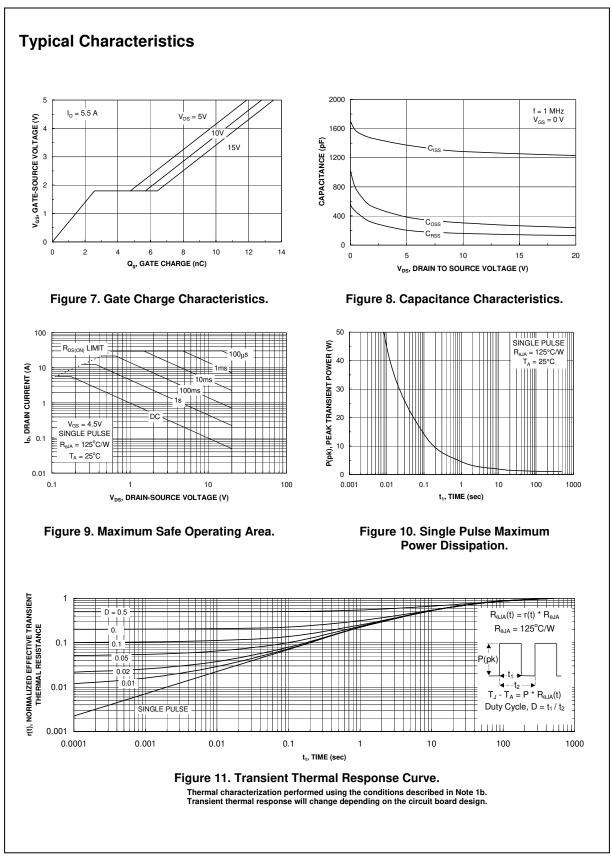
**2.** Pulse Test: Pulse Width <  $300\mu$ s, Duty Cycle < 2.0%

3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

# FDW2501NZ



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